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\*\* CONTINUING DATA \*\*\*\*\*  
*None*  
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\*\* FOREIGN APPLICATIONS \*\*\*\*\*  
 REPUBLIC OF KOREA 2003-35556 06/03/2003  
*yes D.H.K*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED \*\* SMALL ENTITY \*\*  
 \*\* 05/24/2004

Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance <i>[Signature]</i> Examiner's Signature	STATE OR COUNTRY KOREA, REPUBLIC OF	SHEETS DRAWING 3	TOTAL CLAIMS 9	INDEPENDENT CLAIMS 2
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TITLE  
 Field effect transistor using vanadium dioxide layer as channel material and method of manufacturing the field effect transistor

☐ All Fees